

LTC1664

Micropower Quad 10-Bit DAC

FEATURES

- Tiny: 4 DACs in the Board Space of an SO-8
- Micropower: 59µA per DAC Plus 1µA Sleep Mode for Extended Battery Life
- Wide 2.7V to 5.5V Supply Range
- Rail-to-Rail Voltage Outputs Drive 1000pF
- Reference Range Includes Supply for Ratiometric OV-to-V_{CC} Output
- Reference Input Impedance is Code-Independent —Eliminates External Reference Buffer
- Individually Addressable DACs
- Differential Nonlinearity: < ±0.75LSB Max
- Pin-Compatible Octal Version Available (LTC1660)

APPLICATIONS

- Mobile Communications
- Remote Industrial Devices
- Automatic Calibration for Manufacturing
- Portable Battery-Powered Instruments
- Trim/Adjust Applications

BLOCK DIAGRAM

DESCRIPTION

The LTC[®]1664 integrates four accurate, serially addressable 10-bit digital-to-analog converters (DACs) in a tiny 16-pin Narrow SSOP package. Each buffered DAC draws just 59 μ A total supply current, yet is capable of supplying DC output currents in excess of 5mA and reliably driving capacitive loads of up to 1000pF. Sleep mode further reduces total supply current to 1 μ A.

Linear Technology's proprietary, inherently monotonic voltage interpolation architecture provides excellent linearity while allowing for an exceptionally small external form factor.

Ultralow supply current, power-saving Sleep mode and extremely compact size make the LTC1664 ideal for battery-powered applications, while its ease of use, high performance and wide supply range make it an excellent choice as a general-purpose converter.

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Differential Nonlinearity (DNL)





ABSOLUTE MAXIMUM RATINGS

(Note 1)
V_{CC} to GND
Logic Inputs to GND0.3V to 7.5V
V _{OUT A} , V _{OUT B} V _{OUT D} ,
REF to GND $-0.3V$ to (V _{CC} + 0.3V)
Maximum Junction Temperature 125°C
Operating Temperature Range
LTC1664C 0°C to 70°C
LTC1664I –40°C to 85°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{CC} = 2.7V to 5.5V, V_{REF} \leq V_{CC}, V_{OUT} unloaded, unless otherwise noted.

SYMBOL	PARAMETER	ARAMETER CONDITONS		MIN	ТҮР	MAX	UNITS	
Accuracy								
	Resolution			10			Bits	
	Monotonicity	(Notes 2, 4)	•	10			Bits	
DNL	Differential Nonlinearity	(Notes 2, 4)	•		±0.2	±0.75	LSB	
INL	Integral Nonlinearity	(Notes 2, 4)	•		±0.6	±2.5	LSB	
V _{OS}	Offset Error	(Note 7)			±10	±30	mV	
	V _{OS} Temperature Coefficient		•		±15		µV/°C	
FSE	Full-Scale Error	V _{CC} = 5V, V _{REF} = 4.096V (Note 4)			±3	±15	LSB	
	Full-Scale Error Temperature Coefficient		•		±30		µV/°C	
PSR	Power Supply Rejection	V _{REF} = 2.5V			0.18		LSB/V	
Reference	e Input							
	Input Voltage Range			0		V _{CC}	V	
	Resistance	Not in Sleep Mode	•	70	130		kΩ	
	Capacitance				12		pF	
I _{REF}	Reference Current	Sleep Mode	•		0.001	1	μA	
Power Su	pply							
V _{CC}	Positive Supply Voltage		•	2.7		5.5	V	
I _{CC}	Supply Current	V _{CC} = 5V (Note 3) V _{CC} = 3V (Note 3) Sleep Mode (Note 3)	•		236 186 1	380 290 3	μΑ μΑ μΑ	



ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
DC Perfor	mance	·					<u>. </u>
	Short-Circuit Current Low	$V_{OUT} = 0V, V_{CC} = 5.5V, V_{REF} = 5.1V,$ Code = 1023 (Note 9)	•	10	30	100	mA
	Short-Circuit Current High	$V_{OUT} = V_{CC} = 5.5V, V_{REF} = 5.1V, Code = 0$ (Note 9)	•	10	27	120	mA
AC Perfor	mance						
	Voltage Output Slew Rate	Rising (Notes 4, 5) Falling (Notes 4, 5)			0.60 0.25		V/µs V/µs
	Voltage Output Settling Time	$ \begin{array}{l} \mbox{Rising 0.1V}_{FS} \mbox{ to 0.9V}_{FS} \pm 0.5 \mbox{LSB (Notes 4, 5)} \\ \mbox{Falling 0.9V}_{FS} \mbox{ to 0.1V}_{FS} \pm 0.5 \mbox{LSB (Notes 4, 5)} \end{array} $			6 19		μs μs
	Capacitive Load Driving				1000		pF
Digital I/O							
V _{IH}	Digital Input High Voltage	V _{CC} = 2.7V to 5.5V V _{CC} = 2.7V to 3.6V	•	2.4 2.0			V V
V _{IL}	Digital Input Low Voltage	V _{CC} = 4.5V to 5.5V V _{CC} = 2.7V to 5.5V	•			0.8 0.6	V V
V _{OH}	Digital Output High Voltage	$I_{OUT} = -1mA, D_{OUT} Only$	•	V _{CC} – 1			V
V _{OL}	Digital Output Low Voltage	I _{OUT} = 1mA, D _{OUT} Only	•			0.4	V
I _{LK}	Digital Input Leakage	$V_{IN} = GND$ to V_{CC}	•		0.05	±10	μA
C _{IN}	Digital Input Capacitance				2		pF

TIMING CHARACTERISTICS The \bullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (See Figure 1)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{CC} = 4.5\	/ to 5.5V	L					
t ₁	D _{IN} Valid to SCK Setup		•	40	15		ns
t ₂	D _{IN} Valid to SCK Hold		•	0	-11		ns
t ₃	SCK High Time	(Note 6)	•	30	5		ns
t ₄	SCK Low Time	(Note 6)	•	30	7		ns
t ₅	CS/LD Pulse Width	(Note 6)	•	80	30		ns
t ₆	LSB SCK High to $\overline{\text{CS}}$ /LD High	(Note 6)	•	30	4		ns
t7	CS/LD Low to SCK High	(Note 6)	•	80	26		ns
t ₈	D _{OUT} Propagation Delay	C _{LOAD} = 15pF (Note 6)	•	5	26	80	ns
t ₉	SCK Low to CS/LD Low	(Note 6)	•	20	0		ns
t ₁₀	CLR Pulse Width	(Note 6)	•	100	37		ns
t ₁₁	CS/LD High to SCK Positive Edge	(Note 6)	•	30	0		ns
	SCK Frequency	(Notes 6 and 8)	•			16.7	MHz
V _{CC} = 2.7\	/ to 5.5V						
t ₁	D _{IN} Valid to SCK Setup	(Note 6)	•	60	20		ns
t ₂	D _{IN} Valid to SCK Hold	(Note 6)	•	0	-14		ns
t ₃	SCK High Time	(Note 6)	•	50	8		ns
t ₄	SCK Low Time	(Note 6)	•	50	12		ns



TIMING CHARACTERISTICS The \bullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (See Figure 1)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
t ₅	CS/LD Pulse Width	(Note 6)	•	100	30		ns
t ₆	LSB SCK High to CS/LD High	(Note 6)	•	50	5		ns
t ₇	CS/LD Low to SCK High	(Note 6)	•	100	27		ns
t ₈	D _{OUT} Propagation Delay	C _{LOAD} = 15pF (Note 6)	•	5	47	150	ns
t9	SCK Low to CS/LD Low	(Note 6)	•	30	0		ns
t ₁₀	CLR Pulse Width	(Note 6)	•	120	41		ns
t ₁₁	CS/LD High to SCK Positive Edge	(Note 6)	•	30	0		ns
	SCK Frequency	(Notes 6 and 8)	•			10	MHz

Note 1: Absolute maximum ratings are those values beyond which the life of a device may be impaired.

Note 2: Nonlinearity and monotonicity are defined and tested at $V_{CC} = 5V$, V_{REF} = 4.096V, from code 20 to code 1023. See Rail-to-Rail output considerations.

Note 3: Digital inputs at OV or V_{CC}.

Note 4: Load is $10k\Omega$ in parallel with 100pF.

Note 5: $V_{CC} = V_{REF} = 5V$.

Note 6: Guaranteed by design and not subject to test.

Note 7: Measured at code 20.

Note 8: If a continuous clock is used, \overline{CS}/LD timing (t₇ and t₉) will limit the maximum clock frequency to 5MHz at 4.5V to 5.5V(3.85MHz at 2.7V to 5.5V).

Note 9: Any output shorted.

TYPICAL PERFORMANCE CHARACTERISTICS





TYPICAL PERFORMANCE CHARACTERISTICS



1664 G04



1664 G03

PIN FUNCTIONS

GND (Pin 1): System Ground.

V_{OUT A} to V_{OUT D} (Pins 2–5): DAC Analog Voltage Outputs. The output range is

0 to
$$\left(\frac{1023}{1024}\right)$$
 V_{REF}

REF (Pin 6): Reference Voltage Input. $0V \le V_{REF} \le V_{CC}$.

 $\overline{\text{CS}/\text{LD}}$ (Pin 7): Serial Interface Chip Select/Load Input. When $\overline{\text{CS}/\text{LD}}$ is low, SCK is enabled for shifting data on D_{IN} into the register. When $\overline{\text{CS}/\text{LD}}$ is pulled high, SCK is disabled and data is loaded from the shift register into the specified DAC register(s), updating the analog output(s). CMOS and TTL compatible.

SCK (Pin 8): Serial Interface Clock Input. CMOS and TTL compatible.

 \mathbf{D}_{IN} (Pin 9): Serial Interface Data Input. Data on the \mathbf{D}_{IN} pin is shifted into the 16-bit register on the rising edge of SCK. CMOS and TTL compatible.

 D_{OUT} (Pin 10): Serial Interface Data Output. Data appears on D_{OUT} 16 positive SCK edges after being applied to D_{IN} . May be tied to D_{IN} of another serial device for daisy-chain operaton. CMOS and TTL compatible.

CLR (Pin 11): Asynchronous Clear Input. All internal shift and DAC registers are cleared to zero at the falling edge of the CLR signal, forcing the analog outputs to zero scale. CMOS and TTL compatible.

NC (Pins 12–15): Make no electrical connection to these pins.

V_{CC} (Pin 16): Supply Voltage Input. $2.7V \le V_{CC} \le 5.5V$.



BLOCK DIAGRAM



TIMING DIAGRAM



Figure 1



Transfer Function

The transfer function is

$$V_{OUT(IDEAL)} = \left(\frac{k}{1024}\right) V_{REF}$$

where k is the decimal equivalent of the binary DAC input code and V_{REF} is the voltage at REF (Pin 6).

Power-On Reset

The LTC1664 clears the outputs to zero scale when power is first applied, making system initialization consistent and repeatable.

Power Supply Sequencing

The voltage at REF (Pin 6) should be kept within the range $-0.3V \le V_{REF} \le V_{CC} + 0.3V$ (see Absolute Maximum Ratings). Particular care should be taken to observe these limits during power supply turn-on and turn-off sequences, when the voltage at V_{CC} (Pin 16) is in transition. If it is not possible to sequence the supplies, connect a Schottky diode from REF (anode) to V_{CC} (cathode).

Serial Interface

Referring to Figure 2: With $\overline{\text{CS}}/\text{LD}$ held low, data on the D_{IN} input is shifted into the 16-bit shift register on the positive edge of SCK. The 4-bit DAC address, A3-A0, is loaded first (see Table 2), then the 10-bit input code, D9-D0, ordered MSB-to-LSB in each case. Two don't-care bits, X1-X0, are loaded last. When the full 16-bit input word has been shifted in, $\overline{\text{CS}}/\text{LD}$ is pulled high, loading the DAC register with the word and causing the addressed DAC output(s) to update. The clock is disabled internally when $\overline{\text{CS}}/\text{LD}$ is pulled low.

The buffered serial output of the shift register is available on the D_{OUT} pin, which swings from GND to V_{CC} . Data appears on D_{OUT} 16 positive SCK edges after being applied to D_{IN} .

Multiple LTC1664's can be controlled from a single 3-wire serial port (i.e., SCK, D_{IN} and \overline{CS}/LD) by using the included "daisy-chain" facility. A series of *m* chips is configured by connecting each D_{OUT} (except the last) to D_{IN} of the next chip, forming a single 16*m*-bit shift register. The SCK and \overline{CS}/LD signals are common to all chips in the chain. In use, \overline{CS}/LD is held low while *m* 16-bit words are clocked to D_{IN} of the first chip; \overline{CS}/LD is then pulled high, updating all of them simultaneously.

Sleep Mode

DAC address 1110_b is reserved for the special Sleep instruction (see Table 2). In this mode, the digital interface stays active while the analog circuits are disabled; static power consumption is thus virtually eliminated. The reference input and analog outputs are set in a high impedance state and all DAC settings are retained in memory so that when Sleep mode is exited, the outputs of DACs not updated by the Wake command are restored to their last active state.

Sleep mode is initiated by performing a load sequence to address 1110_b (the DAC input word D9-D0 is ignored). Once in Sleep mode, a load sequence to any other address (including "No Change" address 0000_b) causes the LTC1664 to Wake. It is possible to keep one or more chips of a daisy chain in continuous Sleep mode by giving the Sleep instruction to these chips each time the active chips in the chain are updated.

Table 1. LTC1664 Input Word

A3	A2	A1	A0	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	X1	X0
Ado	iress	c/Cor	ntrol				I	nput	Cod	e				Do	n't ire







Table 2.	Table Z. DAG Audiess/Collifor Functions								
A	DDRESS	/CONTR()L						
A3	A2	A1	AO	DAC STATUS	SLEEP STATUS				
0	0	0	0	No Change	Wake				
0	0	0	1	Load DAC A	Wake				
0	0	1	0	Load DAC B	Wake				
0	0	1	1	Load DAC C	Wake				
0	1	0	0	Load DAC D	Wake				
0	1	0	1	Rese	erved				
0	1	1	0	Reserved					
0	1	1	1	Reserved					
1	0	0	0	Rese	erved				
1	0	0	1	Rese	erved				
1	0	1	0	Rese	erved				
1	0	1	1	Rese	erved				
1	1	0	0	Rese	erved				
1	1	0	1	Reserved					
1	1	1	0	No Change	Sleep				
1	1	1	1	Load ALL DACs with Same 10-Bit Code	Wake				

Table 2. DAC Address/Control Functions



Voltage Outputs

Each of the four rail-to-rail output amplifiers contained in the LTC1664 can source or sink up to 5mA. The outputs swing to within a few millivolts of either supply rail when unloaded and have an equivalent output resistance of 85Ω when driving a load to the rails. The output amplifiers are stable driving capacitive loads of up to 1000pF.

A small resistor placed in series with the output can be used to achieve stability for any load capacitance. A 1μ F load can be successfully driven by inserting a 20Ω resistor; a 2.2μ F load needs only a 10Ω resistor. In either case, larger values of resistance, capacitance or both may be safely substituted for the values given.

Rail-to-Rail Output Considerations

In any rail-to-rail voltage output DAC, the output is limited to voltages within the supply range.

If the DAC offset is negative, the output for the lowest codes limits at OV as shown in Figure 3b.

Similarly, limiting can occur near full scale when the REF pin is tied to V_{CC}. If V_{REF} = V_{CC} and the DAC full-scale error (FSE) is positive, the output for the highest codes limits at V_{CC} as shown in Figure 3c. No full-scale limiting can occur if V_{REF} is less than V_{CC} – FSE.

Offset and linearity are defined and tested over the region of the DAC transfer function where no output limiting can occur.





Figure 3. Effects of Rail-to-Rail Operation On a DAC Transfer Curve. (a) Overall Transfer Function (b) Effect of Negative Offset for Codes Near Zero Scale (c) Effect of Positive Full-Scale Error for Input Codes Near Full Scale When $V_{REF} = V_{CC}$



TYPICAL APPLICATIONS



A Low Power Dual Trim Circuit with Coarse/Fine Adjustment

$$V_{OUT 1} = V_{REF} \left(\frac{CODE A}{1024} + \frac{R1}{R2} \frac{CODE B}{1024} \right)$$

= 2.5V $\left(\frac{CODE A}{1024} + \frac{1}{100} \frac{CODE B}{1024} \right)$
$$V_{OUT 2} = V_{REF} \left(\frac{CODE D}{1024} + \frac{R1}{R2} \frac{CODE C}{1024} \right)$$

= 2.5V $\left(\frac{CODE D}{1024} + \frac{1}{100} \frac{CODE C}{1024} \right)$



TYPICAL APPLICATIONS



A 4-Channel Bipolar Output Voltage Circuit Configuration



PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.





** DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

GN16 (SSOP) 1098



PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.



N Package 16-Lead PDIP (Narrow 0.300)

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

N16 1098



TYPICAL APPLICATION



An 11-Bit Pin Driver V_H and V_L Adjustment Circuit for ATE Applications

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1665/LTC1660	Octal 8/10-Bit V _{OUT} DAC in 16-Pin Narrow SSOP	V _{CC} = 2.7V to 5.5V, 60µA per DAC, Rail-to-Rail Output
LTC1661	Dual 10-Bit V _{OUT} DAC in 8-Pin MSOP Package	V _{CC} = 2.7V to 5.5V, 60µA per DAC, Rail-to-Rail Output
LTC1662	Ultra Low Power Dual 10-Bit V _{OUT} DAC in 8-Pin MSOP Package	V _{CC} = 2.7V to 5.5V, 1.5µA per DAC, Rail-to-Rail Output
LTC1663	Single 10-Bit V _{OUT} DAC with 2-Wire Interface in SOT-23 Package	V _{CC} = 2.7V to 5.5V, Internal Reference, 60µA
LTC1446/LTC1446L	Dual 12-Bit V_{OUT} DACs in SO-8 Package with Internal Reference	LTC1446: V_{CC} = 4.5V to 5.5V, V_{OUT} = 0V to 4.095V LTC1446L: V_{CC} = 2.7V to 5.5V, V_{OUT} = 0V to 2.5V
LTC1448	Dual 12-Bit V _{OUT} DAC in SO-8 Package	V_{CC} = 2.7V to 5.5V, External Reference Can Be Tied to V_{CC}
LTC1454/LTC1454L	Dual 12-Bit $V_{\mbox{OUT}}$ DACs in SO-16 Package with Added Functionality	LTC1454: V_{CC} = 4.5V to 5.5V, V_{OUT} = 0V to 4.095V LTC1454L: V_{CC} = 2.7V to 5.5V, V_{OUT} = 0V to 2.5V
LTC1458/LTC1458L	Quad 12-Bit Rail-to-Rail Output DACs with Added Functionality	LTC1458: V_{CC} = 4.5V to 5.5V, V_{OUT} = 0V to 4.095V LTC1458L: V_{CC} = 2.7V to 5.5V, V_{OUT} = 0V to 2.5V
LT1460	Micropower Precision Series Reference, 2.5V, 5V, 10V Versions	0.075% Max, 10ppm/°C Max, Only 130µA Supply Current
LTC1590	Dual 12-Bit I _{OUT} DAC in SO-16 Package	V _{CC} = 4.5V to 5.5V, 4-Quadrant Multiplication
LTC1654	Dual 14-Bit DAC in SO-8 Footprint	1LBS DNL, Selectable Speed/Power
LTC1659	Single Rail-to-Rail 12-Bit V_{OUT} DAC in 8-Lead MSOP Package $V_{CC};$ 2.7V to 5.5V	Low Power Multiplying $V_{\rm OUT}$ DAC. Output Swings from GND to REF. REF Input Can Be Tied to $V_{\rm CC}$

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